

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	151564	silicon near substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:54
L2	10	polycrystalline near2 nucleation near5 nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:57
L3	1478	buffer same superlattice\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:57
L4	2	I1 and I2 and I3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:57
L5	102	polycrystalline near2 nucleation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:58
L6	491	nitride-based near semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:58
L7	2	I1 and I3 and I5 and I6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 14:59
L8	3	I1 and I3 and I6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 15:00